

Data Sheet October 12, 2006 FN8171.4

Dual Digitally-Controlled (XDCP™) Potentiometers

FEATURES

- Dual-Two Separate Potentiometers
- 256 Resistor Taps/pot–0.4% Resolution
- SPI Serial Interface for Write, Read, and Transfer **Operations of the Potentiometer Single Supply Device**
- Wiper Resistance, 100Ω typical @ $V_{CC} = 5V$
- 4 Nonvolatile Data Registers for Each Potentiometer
- **Nonvolatile Storage of Multiple Wiper Positions**
- **Power-on Recall Loads Saved Wiper Position on** Power-up.
- Standby Current < 5µA Max
- 50k Ω , 100k Ω Versions of End to End Resistance
- 100 yr. Data Retention
- Endurance: 100,000 Data Changes per Bit per Register
- 24 Ld SOIC, 24 Ld TSSOP
- Low Power CMOS
- Power Supply $V_{CC} = 5V \pm 1\%$ Pb-Free Plus And Available RoHs Compliant) COM / N tell Pb-Free Plus And Available RoHs Compliant)

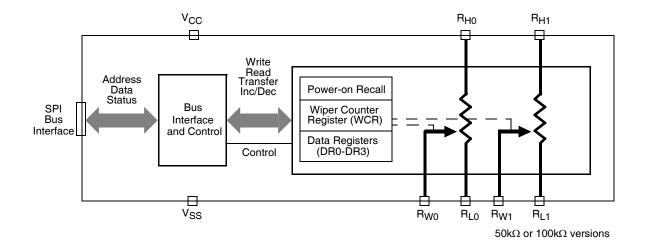
DESCRIPTION

The X9261 integrates controlled 2 digitally (XDCP) on a monolithic CMOS potentiometer integrated circuit.

The digital controlled potentiometer is implemented using 255 resistive elements in a series array. Between each element are tap points connected to the wiper terminal through switches. The position of the wiper on the array is controlled by the user through the SPI bus interface. Each potentiometer has associated with it a volatile Wiper Counter Register (WCR) and four non-volatile Data Registers that can be directly written to and read by the user. The contents of the WCR controls the position of the wiper on the resistor array though the switches. Powerup recalls the contents of the default Data Register (DR0) to the WCR.

The XDCP can be used as a three-terminal potentiometer or as a two terminal variable resistor in a wide variety of applications including control, parameter adjustments, and signal processing.

FUNCTIONAL DIAGRAM

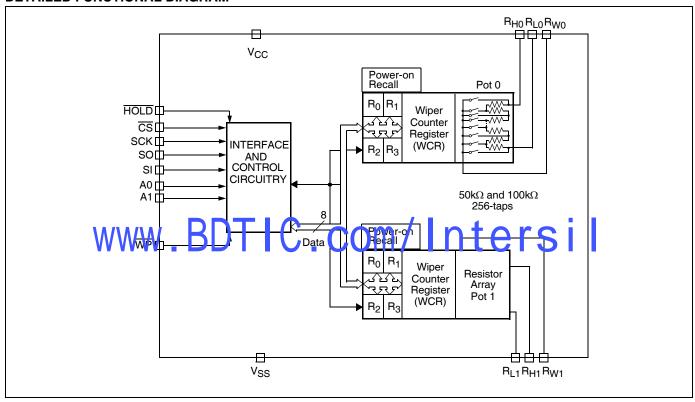


Ordering Information

PART NUMBER	PART MARKING	V _{CC} LIMITS (V)	R _{TOTAL} (kΩ)	TEMP RANGE (°C)	PACKAGE	PKG. DWG. #
X9261US24	X9261US	5 ±10%	50	0 to 70	24 Ld SOIC (300 mil)	M24.3
X9261US24Z (Note)	X9261US Z			0 to 70	24 Ld SOIC (300 mil) (Pb-free)	M24.3
X9261UV24	X9261UV			0 to 70	24 Ld TSSOP (4.4mm)	MDP0044
X9261UV24Z (Note)	X9261UV Z			0 to 70	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

DETAILED FUNCTIONAL DIAGRAM



CIRCUIT LEVEL APPLICATIONS

- · Vary the gain of a voltage amplifier
- Provide programmable dc reference voltages for comparators and detectors
- · Control the volume in audio circuits
- Trim out the offset voltage error in a voltage amplifier circuit
- Set the output voltage of a voltage regulator
- Trim the resistance in Wheatstone bridge circuits
- Control the gain, characteristic frequency and Q-factor in filter circuits
- Set the scale factor and zero point in sensor signal conditioning circuits

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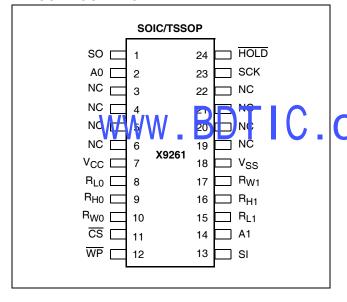
- Vary the frequency and duty cycle of timer ICs
- Vary the dc biasing of a pin diode attenuator in RF circuits
- Provide a control variable (I, V, or R) in feedback circuits

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SYSTEM LEVEL APPLICATIONS

- · Adjust the contrast in LCD displays
- Control the power level of LED transmitters in communication systems
- Set and regulate the DC biasing point in an RF power amplifier in wireless systems
- Control the gain in audio and home entertainment systems
- Provide the variable DC bias for tuners in RF wireless systems
- Set the operating points in temperature control systems
- Control the operating point for sensors in industrial systems
- Trim offset and gain errors in artificial intelligent systems

PIN CONFIGURATION



PIN ASSIGNMENTS

Pin (SOIC/ TSSOP)	Symbol	Function
1	SO	Serial Data Output for SPI bus
2	A0	Device Address for SPI bus.
3	NC	No Connect.
4	NC	No Connect.
5	NC	No Connect.
6	NC	No Connect.
7	V _{CC}	System Supply Voltage
8	R _{L0}	Low Terminal for Potentiometer 0.
9	R _{H0}	High Terminal for Potentiometer 0.
10	R _{W0}	Wiper Terminal for Potentiometer 0.
11	CS	Device Address for SPI bus.
12	WP	Hardware Write Protect
13	SI	Serial Data Input for SPI bus
14	A1	Device Address for SPI bus.
15	R _{L1}	Low Terminal for Potentiometer 1.
16	R _{H1}	High Terminal for Potentiometer 1.
17	R _{W1}	Wiper Terminal for Potentiometer 1.
18	V_{SS}	System Ground
19	NC	No Connect
20	NC	No Connect
21	١C	No Conn ect
22	NC	No Connect
23	SCK	Serial Clock for SPI bus
24	HOLD	Device select. Pause the SPI serial bus.

PIN DESCRIPTIONS

Bus Interface Pins

SERIAL OUTPUT (SO)

SO is a serial data output pin. During a read cycle, data is shifted out on this pin. Data is clocked out by the falling edge of the serial clock.

SERIAL INPUT

SI is the serial data input pin. All opcodes, byte addresses and data to be written to the pots and pot registers are input on this pin. Data is latched by the rising edge of the serial clock.

SERIAL CLOCK (SCK)

The SCK input is used to clock data into and out of the X9261.

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HOLD (HOLD)

HOLD is used in conjunction with the CS pin to select the device. Once the part is selected and a serial sequence is underway, HOLD may be used to pause the serial communication with the controller without resetting the serial sequence. To pause, HOLD must be brought LOW while SCK is LOW. To resume communication, HOLD is brought HIGH, again while SCK is LOW. If the pause feature is not used, HOLD should be held HIGH at all times.

DEVICE ADDRESS (A1 - A0)

The address inputs are used to set the 4-bit slave address. A match in the slave address serial data stream must be made with the address input in order to initiate communication with the X9261.

CHIP SELECT (CS)

When $\overline{\text{CS}}$ is HIGH, the X9261 is deselected and the SO pin is at high impedance, and (unless an internal write cycle is underway) the device will be in the standby state. CS LOW enables the X9261, placing it in the active power mode. It should be noted that after a power-up, a HIGH to LOW transition on $\overline{\text{CS}}$ is required prior to the start of any operation.

R_H, R_L

The R_H and R_L pins are equivalent to the terminal connections on a mechanical potentiometer. Since there are 2 potentiometers, there are 2 sets of R_H and R_L such that R_{H0} and R_{L0} are the terminals of POT 0 and so on.

Rw

The wiper pin are equivalent to the wiper terminal of a mechanical potentiometer. Since there are 2 potentiometers, there are 2 sets of R_W such that R_{W0} is the terminals of POT 0 and so on.

Supply Pins

SYSTEM SUPPLY VOLTAGE (V_{CC}) AND SUPPLY GROUND (VSS)

The V_{CC} pin is the system supply voltage. The V_{SS} pin is the system ground.

Other Pins

NO CONNECT

No connect pins should be left floating. This pins are used for Intersil manufacturing and testing purposes.

HARDWARE WRITE PROTECT INPUT (WP)

The WP pin when LOW prevents nonvolatile writes to the Data Registers.

PRINCIPLES OF OPERATION

Serial Interface

The X9261 supports the SPI interface hardware conventions. The device is accessed via the SI input with data clocked in on the rising SCK. CS must be LOW and the HOLD and WP pins must be HIGH during the entire operation.

The SO and SI pins can be connected together, since they have three state outputs. This can help to reduce system pin count.

Array Description

The X9261 is comprised of a resistor array (See Figure 1). The array contains the equivalent of 255 Potentiometer Pins | C | Series. The physical code of each array are equivalent to the fixed terminals of a mechanical potentiometer $(R_H \text{ and } R_L \text{ inputs}).$

> At both ends of each array and between each resistor segment is a CMOS switch connected to the wiper (R_W) output. Within each individual array only one switch may be turned on at a time.

> These switches are controlled by a Wiper Counter Register (WCR). The 8-bits of the WCR (WCR[7:0]) are decoded to select, and enable, one of 256 switches (See Table 1).

Power-up and Down Requirements.

There are no restrictions on the power-up or powerdown conditions of V_{CC} and the voltages applied to the potentiometer pins provided that V_{CC} is always more positive than or equal to VH, VL, and VW, i.e., V_{CC}, V_H, V_L, V_W. The V_{CC} ramp rate specification is always in effect.

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One of Two Potentiometers SERIAL SERIAL DATA PATH BUS FROM INTERFACE **INPUT CIRCUITRY** С REGISTER 0 **REGISTER 1** 0 (DR1) (DR0) Ν **PARALLEL** Т BUS E R **INPUT REGISTER 2 REGISTER 3 WIPER** D (DR2) (DR3) E COUNTER **REGISTER** 0 (WCR) D INC/DEC **LOGIC** IF WCR = 00[H] THEN RW = RI UP/DN IF WCR = FF[H] THEN RW = RH UP/DN MODIFIED SCK CLK Rw

Figure 1. Detailed Potentiometer Block Diagram

DEVICE DESCRIPTION

Wiper Counter Register (WCF))

The X9261 contains two Wiper Counter Registers, one for each DCP potentiometer. The Wiper Counter Register can be envisioned as a 8-bit parallel and serial load counter with its outputs decoded to select one of 256 switches along its resistor array. The contents of the WCR can be altered in four ways: it may be written directly by the host via the Write Wiper Counter Register instruction (serial load); it may be written indirectly by transferring the contents of one of four associated data registers via the XFR Data Register instruction (parallel load); it can be modified one step at a time by the Increment/Decrement instruction (See Instruction section for more details). Finally, it is loaded with the contents of its Data Register zero (DR0) upon power-up.

The Wiper Counter Register is a volatile register; that is, its contents are lost when the X9261 is powereddown. Although the register is automatically loaded with the value in DR0 upon power-up, this may be different from the value present at power-down. Power-up guidelines are recommended to ensure proper loadings of the DR0 value into the WCR.

Data Registers (DR)

Each potentiometer has four 8-bit nonvolatile Data Registers. These carrive read or written directly by the host. Data can also be transfered between any of the four Data Registers and the associated Wiper Counter Register. All operations changing data in one of the Data Registers is a nonvolatile operation and will take a maximum of 10ms.

If the application does not require storage of multiple settings for the potentiometer, the Data Registers can be used as regular memory locations for system parameters or user preference data.

Bits [7:0] are used to store one of the 256 wiper positions or data (0~255).

Status Register (SR)

This 1-bit Status Register is used to store the system status.

WIP: Write In Progress status bit, read only.

- When WIP=1, indicates that high-voltage write cycle is in progress.
- When WIP=0, indicates that no high-voltage write cycle is in progress.

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Table 1. Wiper Counter Register, WCR (8-bit), WCR[7:0]: Used to store the current wiper position (Volatile, V).

WCR7	WCR6	WCR5	WCR4	WCR3	WCR2	WCR1	WCR0
V	V	V	V	V	V	V	V
(MSB)							(LSB)

Table 2. Data Register, DR (8-bit), Bit [7:0]: Used to store wiper positions or data (Nonvolatile, NV).

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
NV							
MSB							LSB

DEVICE DESCRIPTION

Instructions

IDENTIFICATION BYTE (ID AND A)

The first byte sent to the X9261 from the host, following a \overline{CS} going HIGH to LOW, is called the Identification Byte. The most significant four bits of the slave address are a device type identifier. The ID[3:0] bits is the device id for the X9261; this is fixed as 0101[B] (refer to Table 3).

The AD[3:0] bits in the ID byte is the internal slave address. The physical device address is defined by the state of the 13-140 nput pins. The slave address is externally specified by the user. The 2261 compares the serial data stream with the address

input state; a successful compare of both address bits is required for the X9261 to successfully continue the command sequence. Only the device which slave address matches the incoming device address sent by the master executes the instruction. The A3-A0 inputs can be actively driven by CMOS input signals or tied to $V_{\rm CC}$ or $V_{\rm SS}$.

INSTRUCTION BYTE (I[3:0])

The next byte sent to the X9261 contains the instruction and register pointer information. The three most significant bits are used provide the instruction opcode (I[3:0]). The RB and RA bits point to one of the four Data Registers of each associated XDCP. The least significant bit point to one of two Wiper Counter Registers or Pots. The format is shown below in Table 4.

Table 3. Identification Byte Format

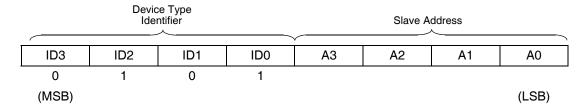
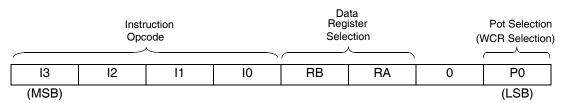


Table 4. Instruction Byte Format



Register Selection

Register Selected	RB	RA
DR0	0	0
DR1	0	1
DR2	1	0
DR3	1	1

DEVICE DESCRIPTION

Instructions

Four of the ten instructions are three bytes in length. These instructions are:

- Read Wiper Counter Register read the current wiper position of the selected potentiometer,
- Write Wiper Counter Register change current wiper position of the selected potentiometer,
- Read Data Register read the contents of the selected Data Register;
- Write Data Register write a new value to the selected Data Register.
- Read Status This command returns the contents of the WIP bit which indicates if the internal write cycle is in progress.

The basic sequence of the three by enstructions is illustrated in Figure 13. These three-byte in structions exchange data between the WCR and one of the Data Registers. A transfer from a Data Register to a WCR is essentially a write to a static RAM, with the static RAM controlling the wiper position. The response of the wiper to this action will be delayed by twRL. A transfer from the WCR (current wiper position), to a Data Register is a write to nonvolatile memory and takes a minimum of twR to complete. The transfer can occur between one of the two potentiometers and one of its associated registers; or it may occur globally, where the transfer occurs between all potentiometers and one associated register. The Read Status Register instruction is the only unique format (See Figure 5).

Four instructions require a two-byte sequence to complete. These instructions transfer data between the host and the X9261; either between the host and one of the data registers or directly between the host and the Wiper Counter Register. These instructions are:

- XFR Data Register to Wiper Counter Register –
 This transfers the contents of one specified Data
 Register to the associated Wiper Counter Register.
- XFR Wiper Counter Register to Data Register –
 This transfers the contents of the specified Wiper
 Counter Register to the specified associated Data
 Register.
- Global XFR Data Register to Wiper Counter
 Register This transfers the contents of all specified Data Registers to the associated Wiper Counter
 Registers.
- Global XFR Wiper Counter Register to Data
 Register This transfers the contents of all Wiper
 Counter Registers to the specified associated Data
 Registers.

INCREMENT/DECREMENT COMMAND

The final command is Increment/Decrement (See Figures 6 and 7). The Increment/Decrement command is different from the other commands. Once the command is issued and the X9261 has responded with an acknowledge, the master can clock the selected wiper up and/or down in one segment steps; thereby, providing a fine tuning capability to the host. For each SCL clock pulse (t_{HIGH}) while SI is HIGH, the selected wiper will move one resistor segment towards the Figure 1 terminal. Similarly, for each SCL clock pulse whe sI is LOW, he selected wiper will move one resistor segment towards the R_L terminal. A detailed illustration of the sequence and timing for this operation are shown. See Instruction format for more details.

Figure 2. Two-Byte Instruction Sequence

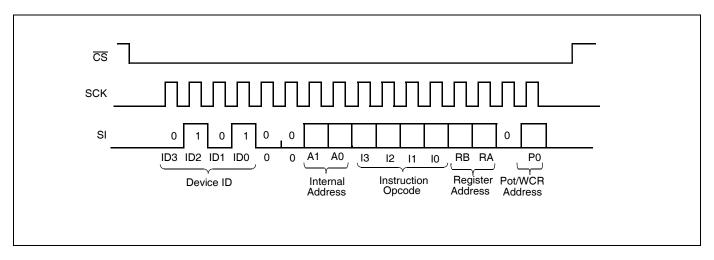


Figure 3. Three-Byte Instruction Sequence (Write)

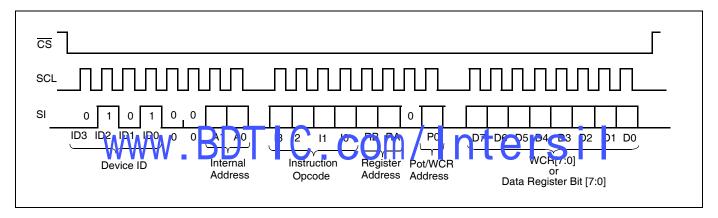


Figure 4. Three-Byte Instruction Sequence (Read)

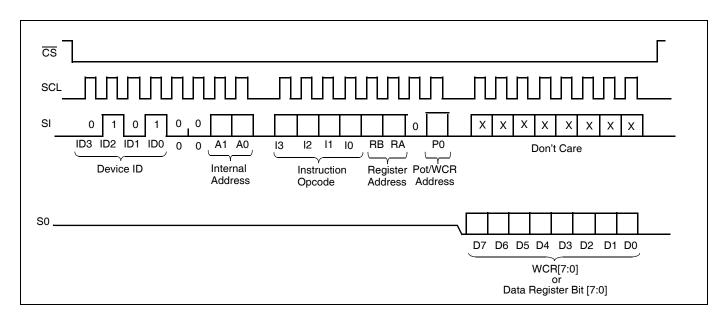


Figure 5. Three-Byte Instruction Sequence (Read Status Register)

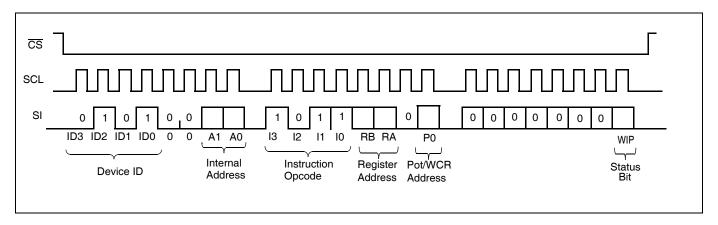


Figure 6. Increment/Decrement Instruction Sequence

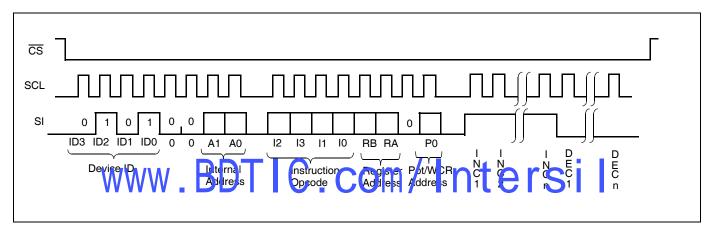


Figure 7. Increment/Decrement Timing Limits

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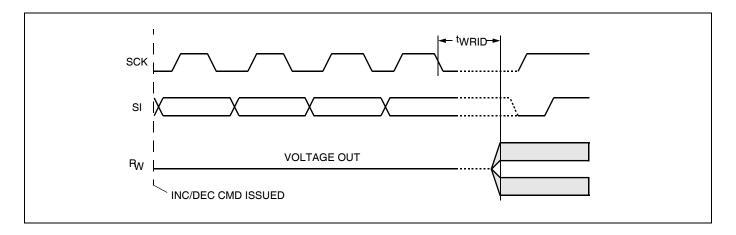


Table 5. Instruction Set

			lr	stru	ction	Set			
Instruction	13	12	I1	10	RB	RA	0	P0	Operation
Read Wiper Counter Register	1	0	0	1	0	0	0	1/0	Read the contents of the Wiper Counter Register pointed to by P0
Write Wiper Counter Register	1	0	1	0	0	0	0	1/0	Write new value to the Wiper Counter Register pointed to by P0
Read Data Register	1	0	1	1	1/0	1/0	0	1/0	Read the contents of the Data Register pointed to by P0 and RB - RA
Write Data Register	1	1	0	0	1/0	1/0	0	1/0	Write new value to the Data Register pointed to by P0 and RB - RA
XFR Data Register to Wiper Counter Register	1	1	0	1	1/0	1/0	0	1/0	Transfer the contents of the Data Register pointed to by P0 and RB - RA to its associated Wiper Counter Register
XFR Wiper Counter Register to Data Register	1	1	1	0	1/0	1/0	0	1/0	Transfer the contents of the Wiper Counter Register pointed to by P0 to the Data Register pointed to by RB - RA
Global XFR Data Registers to Wiper Counter Registers	0	0	0	1	1/0	1/0	0	0	Transfer the contents of the Data Registers pointed to by RB - RA of all four pots to their respective Wiper Counter Registers
Global XFR Wiper Counter Registers to Data Register	1	0	0	0	1/0	1/0	0	0	Transfer the contents of both Wiper Counter Registers to their respective data Registers pointed to by RB - RA of all four pots
Increment/Decrement Wiper Counter Register	0	0	1	0	0	0	0	1/0	Enable Increment/decrement of the Control Latch pointed to by P0

Note: 1/0 = data is one or zero

INSTRUCTION FORMAT BDT IC. com/Intersil Read Wiper Counter Register (WCR)

CS			e Ty tifie	-	A		evice ress				uctic code		A		CR ess	es	(5	ا Sent	Nip t by					D)	CS
Falling Edge	0	1	0	1	0	0	A1	A0	1	0	0	1	0	0	0	P0	WCR7	W C R 6	WCR5	W C R 4	WCR3	W C R 2	W C R 1	WCRO	

Write Wiper Counter Register (WCR)

CS			e Ty tifie	•	Α	Device Addresses				stru Opc			Δ		CR ess	es		(Se		ata by ⊢	-		SI)		CS
Falling Edge	0	1	0	1	0	0	A1	A0	1	0	1	0	0	0	0	P0	W C R 7	W C R 6	W C R 5	W C R 4	WCR3	W C R 2	W C R 1	W C R o	

Read Data Register (DR)

CS Falling			e Ty tifie	•	Α		vice esse			stru Opc				R and			(5	Sen		ata X9	,		SC	D)	CS Rising
Edge	0	1	0	1	0	0	A1	A0	1	0	1	1	RB	RA	0	P0	D 7	D 6	D 5	D 4	D 3	D 2	D 1	0 0	Edge

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Write Data Register (DR)

cs			e Ty itifie	-			evice ress				ucti cod			R and			((Ser		ata y H	,		SI)	CS	TAGE /CLE	
Falling Edge	0	1	0	1	0	0	A1	A0	1	1	0	0	RB	RA	0	P0	D 7	D 6	D 5	D 4	D 3	D 2	D 1	D 0	Rising Edge	HIGH-VOL WRITE C	

Global Transfer Data Register (DR) to Wiper Counter Register (WCR)

CS Falling			e Ty itifie	•	P		vice esse			stru Opc			A	DR ddres	ses	;	CS Rising
Edge	0	1	0	1	0	0	A1	Α0	0	0	0	1	RB	RA	0	0	Edge

Global Transfer Wiper Counter Register (WCR) to Data Register (DR)

CS	De	vice	э Ту	γре		De	evice	:	In	stru	ıctio	on		DR	ì		CS	
Falling	I	den	tifie	r	A	۸dd	ress	es	(Эрс	ode	9	Ad	ddres	ses	3	Rising	HIGH-VOLTAGE
Edge	0	1	0	1	0	0	A1	Α0	1	0	0	0	RB	RA	0	0	Edge	WRITE CYCLE

Transfer Wiper Counter Register (WCR) to Data Register (DR)

CS Falling	De I	vice den	•	•	Δ		evice ress				uctic code			and ddre			CS Rising	HIGH-VOLTAGE WRITE CYCLE
Edge	0	1	0	1	0	0	A1	A0	1	1	1	0	RB	RA	0	P0	Edge	WHITE OTOLL

Transfer Data Register/(DR) t Pyper Counter Register (WCFI) / nters

CS Falling			e Ty itifie	•	ļ	:	evice ress				ode			R and Addre			CS Rising
Edge	0	1	0	1	0	0	A1	Α0	1	1	0	1	RB	RA	0	P0	Edge

Increment/Decrement Wiper Counter Register (WCR)

CS	Device Type				De	vice		In	Instruction				WCR			Increment/Decrement							CS		
Falling	I	den	tifie	r	Δ	ddı	ess	es	(Эрс	ode)	Α	ddr	ess	es	(Sent	by N	Mas	ter	on :	SDA)	Rising
Edge	0	1	0	1	0	0	A1	Α0	0	0	1	0	Χ	Χ	0	P0	I/D	I/D					I/D	I/D	Edge

Read Status Register (SR)

CS	Device Type Device		evice)	In	stru	ıctic	n	WCR			Data Byte						CS							
Falling	I	den	tifie	r	,	Add	ress	es	(Орс	ode)	Ad	ddre	esse	es		(Se	ent l	by X	(926	61 c	n S	O)	Rising
Edge	0	1	0	1	0	0	A1	Α0	0	1	0	1	0	0	0	1	0	0	0	0	0	0	0	WIP	Edge

Notes: (1) "A1 \sim A0": stands for the device addresses sent by the master.

- (2) WPx refers to wiper position data in the Counter Register
- (2) "I": stands for the increment operation, SI held HIGH during active SCK phase (high).
- (3) "D": stands for the decrement operation, SI held LOW during active SCK phase (high).

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ABSOLUTE MAXIMUM RATINGS

Temperature under bias	65°C to +135°C
Storage temperature	65°C to +150°C
Voltage on SCK any address input	
with respect to V _{SS}	1V to +7V
$\Delta V = (V_H - V_L) $	5.5V
Lead temperature (soldering, 10s)	300°C
I _W (10s)	±6mA

COMMENT

Stresses above those listed under "Absolute Maximum" Ratings" may cause permanent damage to the device. This is a stress rating only; the functional operation of the device (at these or any other conditions above those listed in the operational sections of this specification) is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Temp	Min.	Max.
Commercial	0°C	+70°C
Industrial	-40°C	+85°C

Device	Supply Voltage (V _{CC}) ⁽⁴⁾ Limits
X9261	5V ± 10%

POTENTIOMETER CHARACTERISTICS (Over recommended industrial operating conditions unless otherwise stated.)

	Parameter		Lim	nits		
Symbol		Min.	Тур.	Max.	Units	Test Conditions
R _{TOTAL}	End to End Resistance		100		kΩ	T version
R _{TOTAL}	End to End Resistance		50		kΩ	U version
	End to End Resistance Tolerance			±20	%	
	Power Rating			50	mW	25°C, each pot
I _W	Wiper Current			_±3_	mA	
R _W	Wipler/Flesistance		C M	300	Ω	W = ±3mA @ \ + = 3V
R _W	Wiper Resistance	•		150	Ω	I _W = ±3rnA @ V+ = 5V
V _{TERM}	Voltage on any R _H or R _L Pin	V_{SS}		V _{CC}	V	$V_{SS} = 0V$
	Noise		-120		dBV	Ref: 1V
	Resolution		0.4		%	
	Absolute Linearity ⁽¹⁾			±1	MI ⁽³⁾	$R_{w(n)(actual)} - R_{w(n)(expected)}^{(5)}$
	Relative Linearity (2)			±0.6	MI ⁽³⁾	$R_{W(n+1)} - [R_{W(n)+MI}]^{(5)}$
	Temperature Coefficient of R _{TOTAL}		±300		ppm/°C	
	Ratiometric Temp. Coefficient			20	ppm/°C	
C _H /C _L /C _W	Potentiometer Capacitances		10/10/25		pF	See Macro model
l _{al}	R _W , R _H , R _L Leakage		0.1	10.0	μA	Device in stand by. Vin = V _{SS} to V _{CC}

Notes: (1) Absolute linearity is utilized to determine actual wiper voltage versus expected voltage as determined by wiper position when used as a potentiometer.

- (3) MI = RTOT / 255 or $(R_H R_L) / 255$, single pot
- (4) During power-up V_{CC} > V_H, V_L, and V_W. (5) n = 0, 1, 2, ...,255; m = 0, 1, 2, ..., 254.

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⁽²⁾ Relative linearity is utilized to determine the actual change in voltage between two successive tap positions when used as a potentiometer. It is a measure of the error in step size.

D.C. OPERATING CHARACTERISTICS (Over the recommended operating conditions unless otherwise specified.)

			Liı	mits		
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
I _{CC1}	V _{CC} supply current (active)			400	μΑ	f _{SCK} = 2.5 MHz, SO = Open, V _{CC} = 6V Other Inputs = V _{SS}
I _{CC2}	V _{CC} supply current (nonvolatile write)		1	5	mA	f_{SCK} = 2.5MHz, SO = Open, V_{CC} = 6V Other Inputs = V_{SS}
I _{SB}	V _{CC} current (standby)			5	μΑ	$\frac{\text{SCK} = \text{SI} = \text{V}_{\text{SS}}, \text{ Addr.} = \text{V}_{\text{SS}},}{\text{CS}} = \text{V}_{\text{CC}} = 6\text{V}$
ILI	Input leakage current			10	μΑ	$V_{IN} = V_{SS}$ to V_{CC}
ILO	Output leakage current			10	μΑ	V _{OUT} = V _{SS} to V _{CC}
V _{IH}	Input HIGH voltage	V _{CC} x 0.7		V _{CC} + 1	V	
V _{IL}	Input LOW voltage	-1		V _{CC} x 0.3	V	
V _{OL}	Output LOW voltage			0.4	V	I _{OL} = 3mA
V _{OH}	Output HIGH voltage	V _{CC} - 0.8			V	$I_{OH} = -1 \text{mA}, V_{CC} \ge +3 \text{V}$
V _{OH}	Output HIGH voltage	V _{CC} - 0.4			V	$I_{OH} = -0.4$ mA, $V_{CC} \le +3$ V

ENDURANCE AND DATA RETENTION

Parameter	Min.	Units
Minimum endurance	100,000	Data changes per bit per register
Data retention	100	years

CAPACITANCE

Symbol	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	Max.+	∆Unit €	Te st Conditions
C _{OUT} ⁽⁶⁾	Output capacitance (SS)	8	pF	$V_{OUT} = 0V$
C _{IN} ⁽⁶⁾	Input capacitance (A0, A1, SI, CS, WP, HOLD, and SCK)	6	pF	$V_{IN} = 0V$

POWER-UP TIMING

Symbol	Parameter	Min.	Max.	Units
t _r V _{CC} ⁽⁶⁾	V _{CC} Power-up rate	0.2	50	V/ms
t _{PUR} (7)	Power-up to initiation of read operation		1	ms

POWER-UP AND DOWN REQUIREMENTS

The are no restrictions on the power-up or power-down conditions of V_{CC} and the voltages applied to the potentiometer pins provided that V_{CC} is always more positive than or equal to V_H , V_L , and V_W , i.e., $V_{CC} \ge V_H$, V_L , V_W . The V_{CC} power-up timing spec is always in effect.

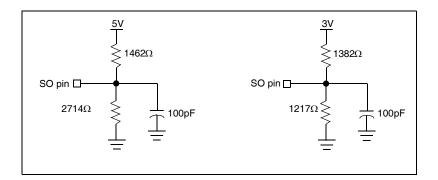
A.C. TEST CONDITIONS

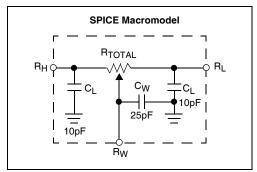
Input Pulse Levels	V _{CC} x 0.1 to V _{CC} x 0.9		
Input rise and fall times	10ns		
Input and output timing level	V _{CC} x 0.5		

Notes: (6) This parameter is not 100% tested

⁽⁷⁾ t_{PUR} and t_{PUW} are the delays required from the time the (last) power supply (V_{CC}-) is stable until the specific instruction can be issued. These parameters are periodically sampled and not 100% tested.

EQUIVALENT A.C. LOAD CIRCUIT





AC TIMING

Symbol	Parameter	Min.	Max.	Units
fsck	SSI/SPI clock frequency		2	MHz
t _{CYC}	SSI/SPI clock cycle rime	500		ns
t _{WH}	SSI/SPI clock high rime	200		ns
t _{WL}	SSI/SPI clock low time	200		ns
t _{LEAD}	Lead time	250		ns
tLAG	Lag time	250		ns
tsu	SI, SCK, HOLD and CS input setup time	50		ns
t _H	SI, SCK, HOLD and CS input hold time	50		ns
t _{RI}	SI, SCK, HOLD and Conjugat rise time	1 0 10	2	μS
t _{Fl}	\$1,50 k, HOLD and CS input fall time	ters	2	μS
t _{DIS}	SO output disable time	0	250	ns
t _V	SO output valid time		200	ns
t _{HO}	SO output hold time	0		ns
t _{RO}	SO output rise time		100	ns
t _{FO}	SO output fall time		100	ns
tHOLD	HOLD time	400		ns
tHSU	HOLD setup time	100		ns
t _{HH}	HOLD hold time	100		ns
tHZ	HOLD low to output in high Z		100	ns
t _{LZ}	HOLD high to output in low Z		100	ns
T _I	Noise suppression time constant at SI, SCK, HOLD and CS inputs		10	ns
t _{CS}	CS deselect time	2		μS
^t WPASU	WP, A0, A1 setup time	0		ns
tWPAH	WP, A0, A1 hold time	0		ns

HIGH-VOLTAGE WRITE CYCLE TIMING

Symbol	Parameter	Тур.	Max.	Units
t _{WR}	High-voltage write cycle time (store instructions)	5	10	ms

XDCP TIMING

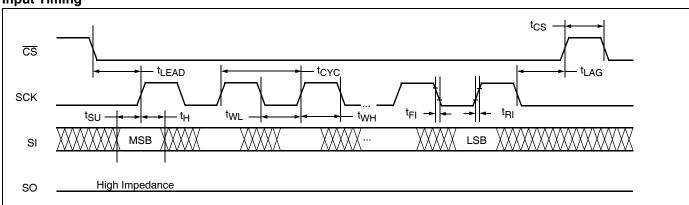
Symbol	Parameter	Min.	Max.	Units
tWRPO	Wiper response time after the third (last) power supply is stable	5	10	μS
t _{WRL}	Wiper response time after instruction issued (all load instructions)	5	10	μS

SYMBOL TABLE

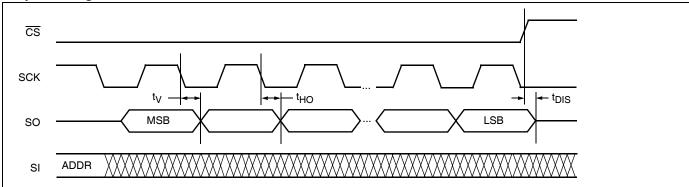
WAVEFORM	INPUTS	OUTPUTS
	Must be steady	Will be steady
	May change from Low to High	Will change from Low to High
	May change from High to Low	Will change from High to Low
	Don't Care: Changes Allowed	Changing: State Not Known
	N/A	Center Line is High Impedance

TIMING DIAGRAMSWW.BDTIC.com/Intersil

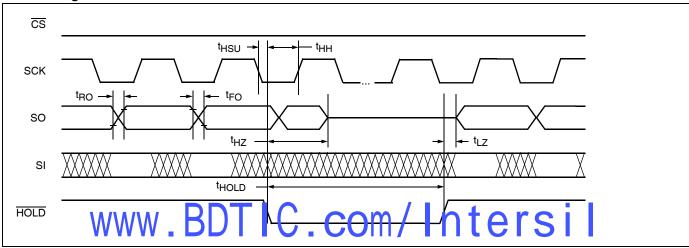
Input Timing



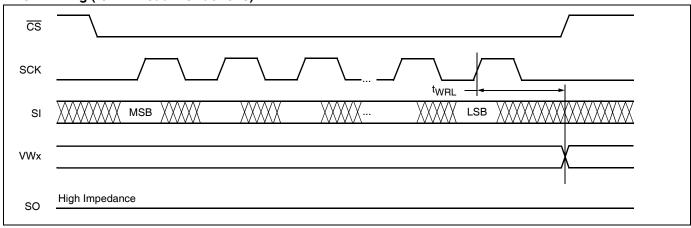




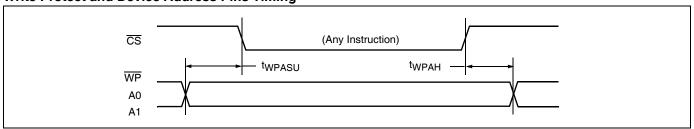
Hold Timing



XDCP Timing (for All Load Instructions)

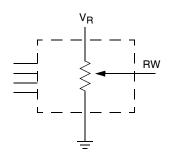


Write Protect and Device Address Pins Timing

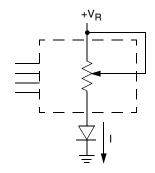


APPLICATIONS INFORMATION

Basic Configurations of Electronic Potentiometers



Three terminal Potentiometer; Variable voltage divider

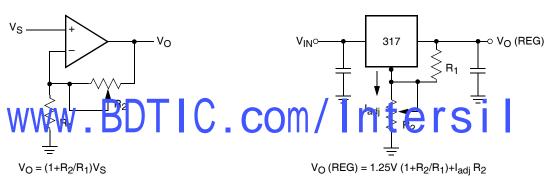


Two terminal Variable Resistor; Variable current

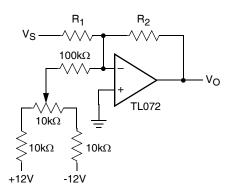
Voltage Regulator

Application Circuits

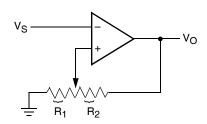
Noninverting Amplifier



Offset Voltage Adjustment



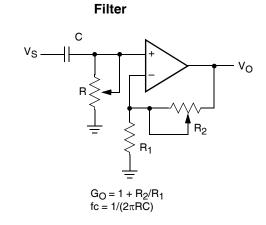
Comparator with Hysterisis



$$\begin{split} &V_{UL} = \{R_1/(R_1 + R_2)\} \ V_O(max) \\ &V_{LL} = \{R_1/(R_1 + R_2)\} \ V_O(min) \end{split}$$

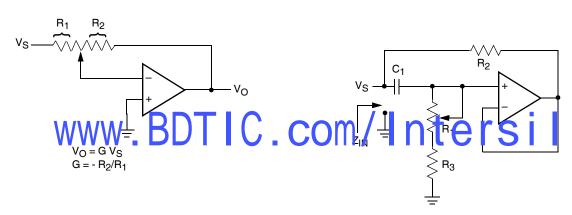
Application Circuits (continued)

Attenuator $V_{S} \xrightarrow{R_{1}} R_{2} = R_{2} = R_{3} = R_{4} = 10k\Omega$ $V_{O} = G V_{S}$ $-1/2 \le G \le +1/2$



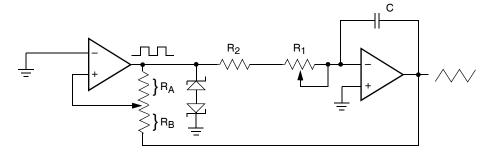
Equivalent L-R Circuit

Inverting Amplifier



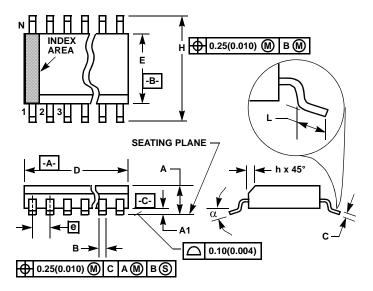
 $Z_{IN} = R_2 + s R_2 (R_1 + R_3) C_1 = R_2 + s Leq$ $(R_1 + R_3) >> R_2$

Function Generator



 $\begin{array}{l} \text{frequency} \propto R_1,\,R_2,\,C \\ \text{amplitude} \propto R_A,\,R_B \end{array}$

Small Outline Plastic Packages (SOIC)



NOTES:

- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs.
 Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer or the rolly suptional lift soft resent, avisual intervious feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
- Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

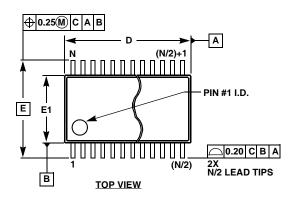
M24.3 (JEDEC MS-013-AD ISSUE C)
24 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE

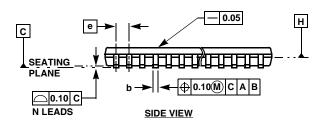
	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	0.0926	0.1043	2.35	2.65	-
A1	0.0040	0.0118	0.10	0.30	-
В	0.013	0.020	0.33	0.51	9
С	0.0091	0.0125	0.23	0.32	-
D	0.5985	0.6141	15.20	15.60	3
Е	0.2914	0.2992	7.40	7.60	4
е	0.05	0.05 BSC		BSC	-
Н	0.394	0.419	10.00	10.65	-
h	0.010	0.029	0.25	0.75	5
L	0.016	0.050	0.40	1.27	6
N	2	4	2	24	7
α	0°	8°	0°	8°	-

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Thin Shrink Small Outline Package Family (TSSOP)





MDP0044

THIN SHRINK SMALL OUTLINE PACKAGE FAMILY

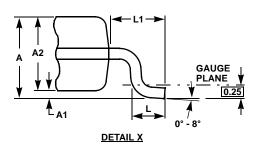
SYMBOL	14 LD	16 LD	20 LD	24 LD	28 LD	TOLERANCE
Α	1.20	1.20	1.20	1.20	1.20	Max
A1	0.10	0.10	0.10	0.10	0.10	±0.05
A2	0.90	0.90	0.90	0.90	0.90	±0.05
b	0.25	0.25	0.25	0.25	0.25	+0.05/-0.06
С	0.15	0.15	0.15	0.15	0.15	+0.05/-0.06
D	5.00	5.00	6.50	7.80	9.70	±0.10
Е	6.40	6.40	6.40	6.40	6.40	Basic
E1	4.40	4.40	4.40	4.40	4.40	±0.10
е	0.65	0.65	0.65	0.65	0.65	Basic
L	0.60	0.60	0.60	0.60	0.60	±0.15
L1	1.00	1.00	1.00	1.00	1.00	Reference

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NOTES:

- 1. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15mm per side.
- 2. Dimension "E1" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm per
- 3. Dimensions "D" and "E1" are measured at dAtum Plane H.
- 4. Dimensioning and tolerancing per ASME Y14.5M-1994.





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